

(Chloromethyl)trimethylsilane at 160 K

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Key indicators

Single-crystal X-ray study
T = 160 K
Mean $\sigma(\text{Si}-\text{C}) = 0.004 \text{ \AA}$
R factor = 0.040
wR factor = 0.115
Data-to-parameter ratio = 23.3For details of how these key indicators were
automatically derived from the article, see
<http://journals.iucr.org/e>.

(Chloromethyl)trimethylsilane, $\text{Me}_3\text{SiCH}_2\text{Cl}$ or $\text{C}_4\text{H}_{11}\text{ClSi}$, is a liquid at room temperature, and it was crystallized using *in situ* methods. The C—Si—C bond angles involving the chloromethyl group are somewhat smaller than those involving only methyl groups [$105.5(2)$ – $109.47(19)^\circ$ versus $110.01(19)$ – $111.2(2)^\circ$], which is ascribable to both the electronegative and the steric effects of the Cl atom.

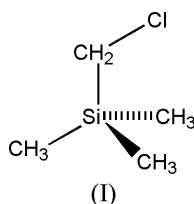
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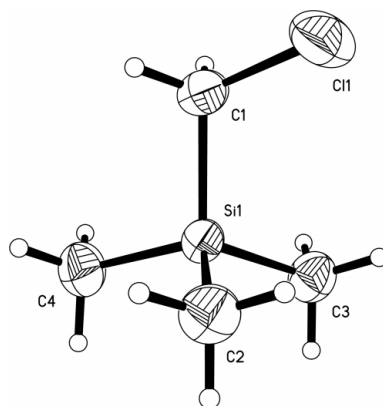
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Comment

(Chloromethyl)trimethylsilane, (I), is a liquid under ambient conditions, and a crystal was obtained by *in situ* crystallization of a sample held in a hand-drawn Pyrex capillary (Boese & Nussbaumer, 1994).



Molecules of (I) adopt the expected tetrahedral configuration at Si (Fig. 1). Si—C bond distances fall into the range $1.848(4)$ – $1.880(4) \text{ \AA}$, although to within experimental error the bond distances and angles have C_s symmetry, with a mirror plane passing through atoms Si1, C1, Cl1 and C4; the C4—Si1—C1—Cl1 torsion angle [$175.3(2)^\circ$] shows a somewhat more significant deviation from the symmetry. The bond angles at atom Si1 involving the more electronegative CH_2Cl group are smaller [$105.5(2)$ – $109.47(19)^\circ$] than those involving only methyl groups [$110.01(19)$ – $111.2(2)^\circ$]. The smaller

**Figure 1**

A view of the molecular structure of (I). Displacement ellipsoids are drawn at the 50% probability level and H atoms are represented as spheres of arbitrary radii.

magnitude of C1–Si1–C4 [105.5 (2)°] relative to C1–Si1–C2 [109.4 (2)°] and C1–Si1–C3 [109.47 (19)°] presumably reflects the steric influence of the Cl atom.

The only intermolecular interactions falling within the sum of the van der Waals radii (Bondi, 1964) of the participating atoms are weak Cl1⋯H33ⁱ [symmetry code (i): $-x, -y, z - \frac{1}{2}$] interactions (2.93 Å; the sum of the van der Waals radii of Cl and H is 2.95 Å). These result in chains that spiral about the 2₁ axis parallel to the *c* direction (Fig. 2).

Experimental

A sample of (I) was obtained from Aldrich and used as received. Compound (I) is a liquid under ambient conditions and it was crystallized *in situ* in a capillary (o.d. 0.34 mm) mounted on the diffractometer. A crystal was grown by first establishing a seed in a small volume of the liquid at 182.8 K, and then cooling at a rate of 10 K h⁻¹. The sample was then cooled to 160 K for data collection.

Crystal data

| | |
|---|-------------------------------------|
| C ₄ H ₁₁ ClSi | Mo <i>K</i> α radiation |
| <i>M_r</i> = 122.67 | Cell parameters from 72 reflections |
| Orthorhombic, <i>Pna</i> 2 ₁ | $\theta = 15\text{--}16^\circ$ |
| <i>a</i> = 13.8776 (13) Å | $\mu = 0.56\text{ mm}^{-1}$ |
| <i>b</i> = 6.3855 (9) Å | <i>T</i> = 160 K |
| <i>c</i> = 8.4000 (10) Å | Cylinder, colourless |
| <i>V</i> = 744.37 (15) Å ³ | 0.50 × 0.39 × 0.39 mm |
| <i>Z</i> = 4 | 0.50 mm length, 0.39 mm radius |
| <i>D_x</i> = 1.095 Mg m ⁻³ | |

Data collection

| | |
|--|--|
| Stoe STADI-4 diffractometer equipped with an Oxford Cryo-systems low-temperature device (Cosier & Glazer, 1986) | 1306 independent reflections |
| ω - θ scans | 1186 reflections with $I > 2\sigma(I)$ |
| Absorption correction: ψ scan [azimuthal absorption correction (North <i>et al.</i> , 1968) applied using <i>XPREP</i> (Sheldrick, 1997)] | <i>R</i> _{int} = 0.030 |
| <i>T</i> _{min} = 0.741, <i>T</i> _{max} = 0.804 | $\theta_{\text{max}} = 25.0^\circ$ |
| 3768 measured reflections | <i>h</i> = -1 → 16 |
| | <i>k</i> = -7 → 7 |
| | <i>l</i> = -9 → 9 |
| | 3 standard reflections |
| | frequency: 60 min |
| | intensity decay: none |

Refinement

| | |
|---|---|
| Refinement on <i>F</i> ² | where $P = 0.3333\max(0, F_o^2) + 0.6667F_c^2$ |
| $R[F^2 > 2\sigma(F^2)] = 0.040$ | $(\Delta/\sigma)_{\text{max}} = 0.001$ |
| $wR(F^2) = 0.115$ | $\Delta\rho_{\text{max}} = 0.43\text{ e \AA}^{-3}$ |
| <i>S</i> = 1.02 | $\Delta\rho_{\text{min}} = -0.32\text{ e \AA}^{-3}$ |
| 1305 reflections | Absolute structure: Flack (1983), |
| 56 parameters | 602 Friedel pairs |
| H-atom parameters constrained | Flack parameter = -0.17 (17) |
| $w = 1/[\sigma^2(F^2) + (0.0706P)^2 + 0.41P]$ | |

Table 1

Selected geometric parameters (Å, °).

| | | | |
|-----------|-------------|------------|-------------|
| Cl1–C1 | 1.798 (5) | Si1–C3 | 1.862 (4) |
| Si1–C1 | 1.880 (4) | Si1–C4 | 1.867 (4) |
| Si1–C2 | 1.848 (4) | | |
| C1–Si1–C2 | 109.4 (2) | C2–Si1–C4 | 111.2 (2) |
| C1–Si1–C3 | 109.47 (19) | C3–Si1–C4 | 111.18 (19) |
| C1–Si1–C4 | 105.5 (2) | Cl1–C1–Si1 | 111.9 (2) |
| C2–Si1–C3 | 110.01 (19) | | |

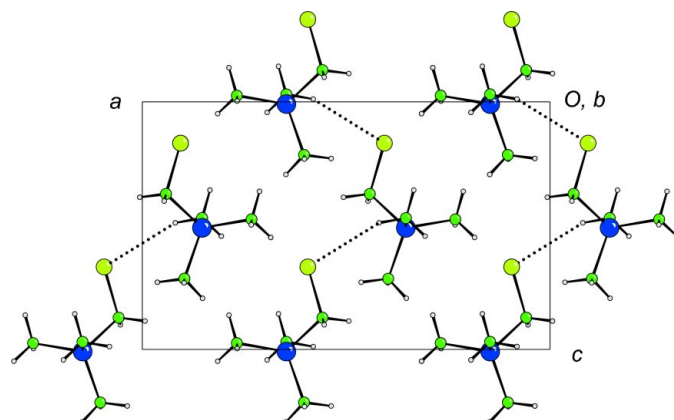


Figure 2

The molecular packing of (I), viewed along the *b* axis. Weak intermolecular Cl1⋯H33 interactions are shown as dotted lines.

The positions of the H atoms were recalculated geometrically after each refinement cycle, using a C–H distance of 1.00 Å, and they were assigned $U_{\text{iso}}(\text{H}) = 1.2U_{\text{eq}}(\text{C})$. The 10,1,0 reflection was omitted as an outlier.

Data collection: *DIF4* (Stoe & Cie, 1990); cell refinement: *DIF4*; data reduction: *REDU4* (Stoe & Cie, 1990); program(s) used to solve structure: *DIRDIF* (Beurskens *et al.*, 1996); program(s) used to refine structure: *CRYSTALS* (Betteridge *et al.*, 2003); molecular graphics: *CAMERON* (Watkin *et al.*, 1996) and *XP* (Sheldrick, 1997); software used to prepare material for publication: *CRYSTALS*, *enCIFer* (CCDC, 2003) and *PLATON* (Spek, 2003) used within *WinGX* (Farrugia, 1999).

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